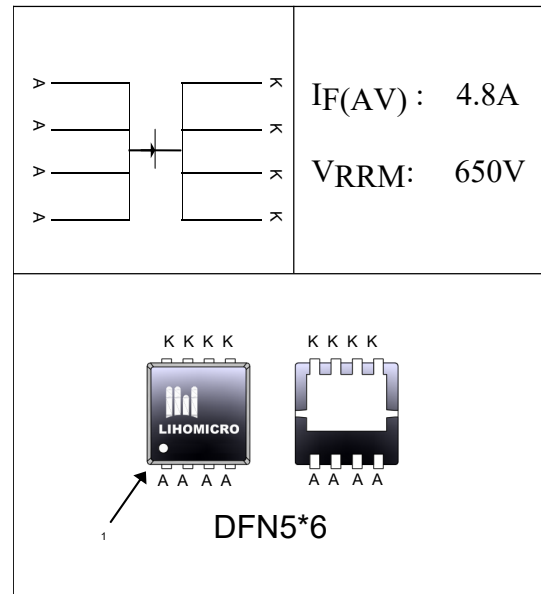


Silicon Carbide Schottky Diode
●Features

- High Surge Current Capacity
- Low Forward Voltage Drop
- Low Power Loss & High Efficiency
- Guard Ring & Environmental Protection
- High Temperature Application
- Green Molding Compound(No Br,Sb)

●Application

- Half-Bridge/Full-Bridge Switched-Mode Power
- PC Power


●Ordering Information:

| | |
|---------------------------------------|----------------------|
| Part Number | LHC04A65 |
| Package | DFN5*6 |
| Basic Ordering Unit (pcs) | 5000 |
| Normal Package Material Ordering Code | LHC04A65N-DFN5*6-TAP |
| Halogen Free Ordering Code | LHC04A65N-DFN5*6-TAP |

●Maximum Ratings Characteristics ($T_A = 25^\circ\text{C}$ Unless otherwise Noted)

| PARAMETER | SYMBOL | Value | UNIT |
|---|-------------|----------|------|
| Repetitive Peak Reverse Voltage | V_{RRM} | 650 | V |
| Working Peak Reverse Voltage | V_{RWM} | 650 | V |
| DC blocking Voltage | V_{RM} | 650 | V |
| Average Rectified Forward Current (Rated VR-20KHz Square Wave)-50% duty cycle | $I_{F(AV)}$ | 4.8 | A |
| Repetitive Peak Forward surge current (surge applied at rated load conditions half wave, single phase, 60Hz) | I_{FSM} | 48 | A |
| Operating Temperature | T_J | -55~+175 | °C |
| Storage Temperature | T_{STG} | -55~+175 | °C |

●Electronic Characteristics

| PARAMETER | SYMBOL | TEST CONDITION | MIN | TYP | MAX | UNIT |
|---------------------------|----------------|-------------------------------------|-----|-----|-----|------|
| Forward Voltage Drop | VF | $I_F=4A, T_J=25^{\circ}C$ | -- | 1.5 | 1.8 | V |
| | | $I_F=4A, T_J=175^{\circ}C$ | -- | 1.8 | 2.0 | |
| Reverse Current | IR | $V_R=V_{RRM}, T_J=25^{\circ}C$ | -- | 1 | 20 | uA |
| | | $V_R=V_{RRM}, T_J=175^{\circ}C$ | -- | 12 | 100 | nA |
| Total Capacitive Charge | Qc | $V_R = 400 V, T_J = 25^{\circ}C$ | -- | 28 | -- | nC |
| Total Capacitance | C _T | $V_R=0V, T_J=25^{\circ}C, f=1MHz$ | -- | 185 | -- | pF |
| | | $V_R=200V, T_J=25^{\circ}C, f=1MHz$ | -- | 19 | -- | |
| | | $V_R=400V, T_J=25^{\circ}C, f=1MHz$ | -- | 67 | -- | |
| Capacitance Stored Energy | Ec | $V_R=400V$ | -- | 2.4 | -- | μJ |

●Thermal Characteristics

| PARAMETER | SYMBOL | MAX | UNIT |
|----------------------------------|-------------------|-----|------|
| Thermal Resistance Junction-case | Rth _{JC} | 2.4 | °C/W |

Note:

1.300Us pulse width 2% duty cycle

2.Thermal Resistance test performed in accordance with JESD-51

●Ratings and Characteristics Curves

Figure 1. Forward Characteristics

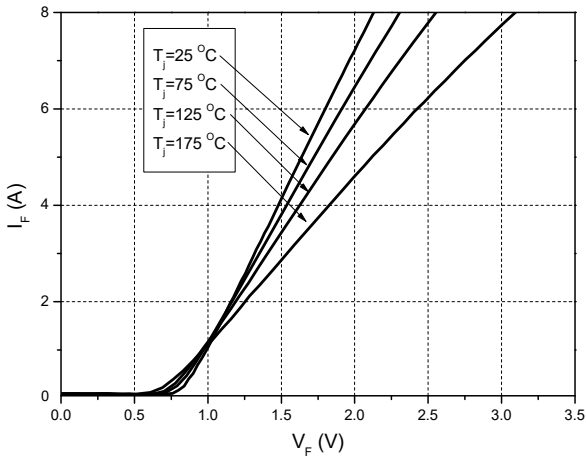


Figure 2. Reverse Characteristics

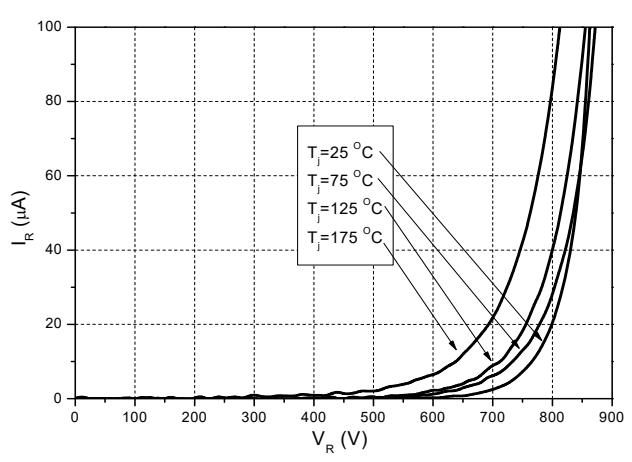


Figure 3. Capacitance vs. Reverse Voltage

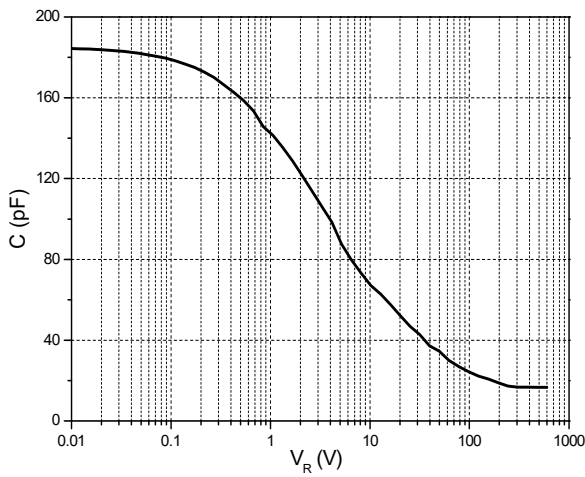
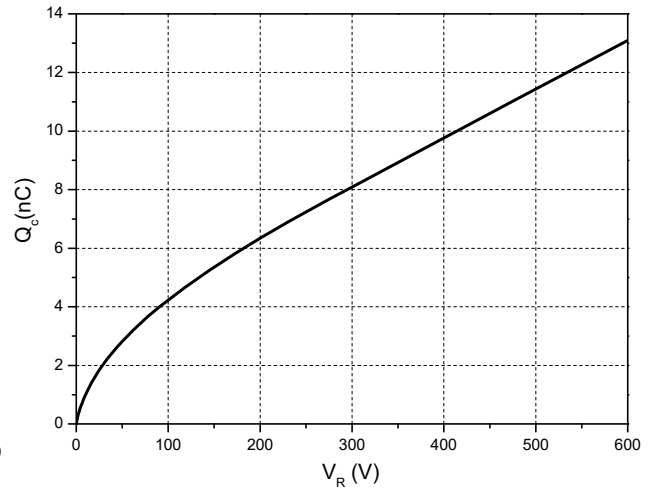


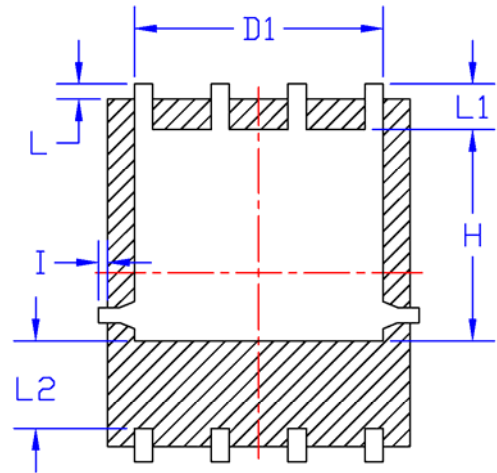
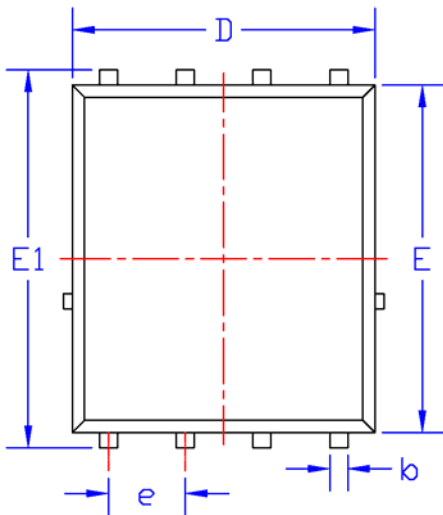
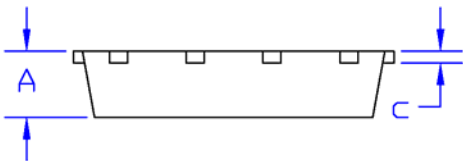
Figure 4. Total Capacitance Charge vs. Reverse Voltage



●Dimensions (DFN5*6)

UNIT:mm

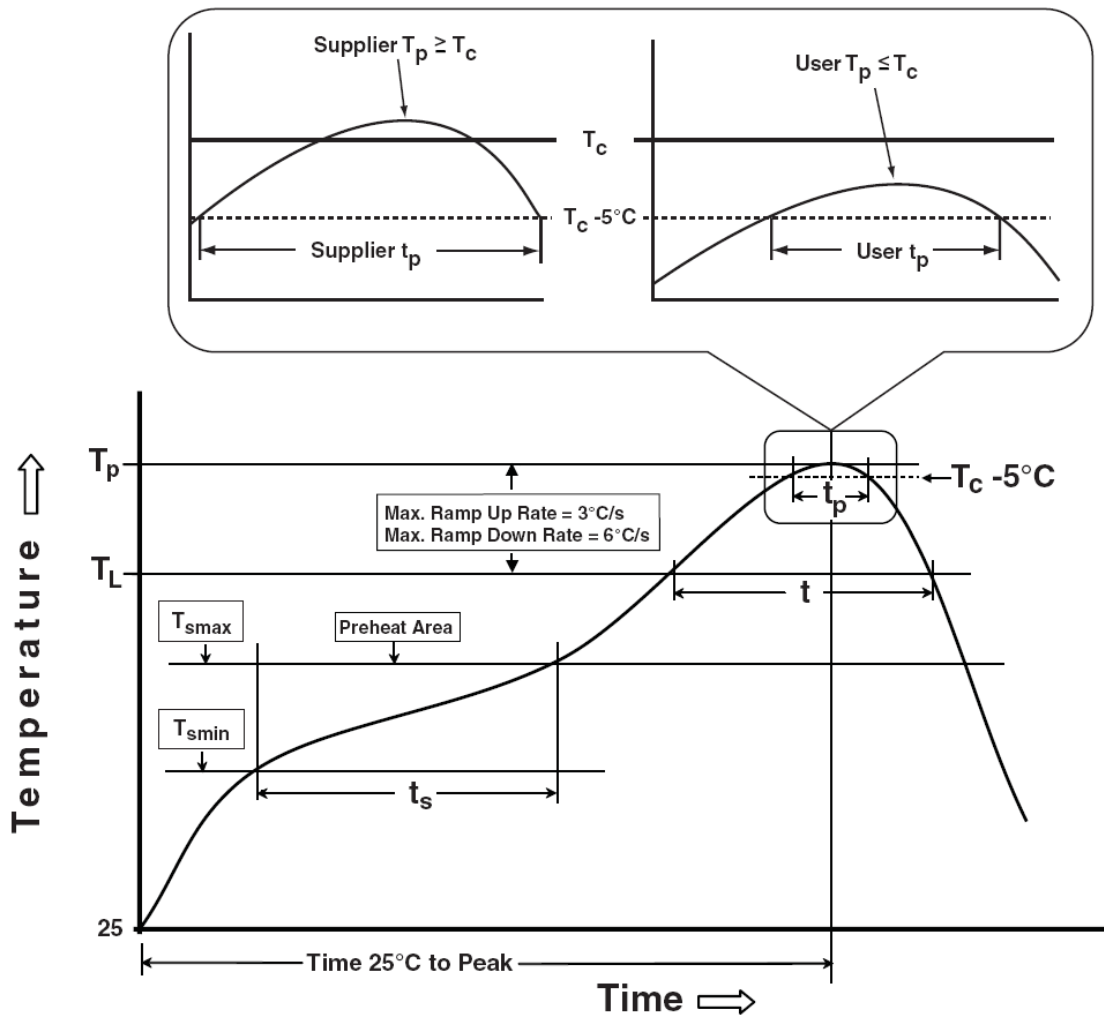
| SYMBOL | min | max | SYMBOL | min | max |
|--------|------|------|--------|---------|------|
| A | 1.00 | 1.20 | e | 1.27BSC | |
| b | 0.30 | 0.50 | L | 0.05 | 0.30 |
| c | 0.20 | 0.30 | L1 | 0.40 | 0.80 |
| D | 4.80 | 5.20 | L2 | 1.20 | 2.00 |
| D1 | 3.90 | 4.30 | H | 3.30 | 3.80 |
| E | 5.50 | 5.90 | I | - | 0.18 |
| E1 | 5.90 | 6.40 | | | |



● **Mechanical**

- Molder Plastic: UL Flammability Classification Rating 94V-0

● **Classification Profile**



● Classification Reflow Profiles

| | | |
|--|---------------|---------------|
| Average ramp-up rate (T_L to T_P) | < 3°C/sec | < 3°C/sec |
| Preheat | | |
| - Temperature Min ($T_{S_{min}}$) | 100°C | 150°C |
| - Temperature Max ($T_{S_{max}}$) | 150°C | 200°C |
| - Time (min to max) (ts) | 60 to 120 sec | 60 to 180 sec |
| $T_{S_{max}}$ to T_L | | |
| - Ramp-up Rate | < 3°C/sec | < 3°C/sec |
| Time maintained above: | | |
| - Temperature (T_L) | 183°C | 217°C |
| - Time (t_L) | 60 to 150 sec | 60 to 150 sec |
| Peak Temperature (T_P) | 240°C +0/-5°C | 260°C +0/-5°C |
| Time within 5°C of actual Peak Temperature (t_P) | 10 to 30 sec | 20 to 40 sec |
| Ramp-down Rate | < 6°C/sec | < 6°C/sec |
| Time 25°C to Peak Temperature | < 6 minutes | < 8 minutes |

Flow (wave) soldering (solder dipping)

| Products | Peak Temperature | Dipping Time |
|------------------|------------------|--------------|
| Pb devices. | 245°C ±5°C | 5sec ±1sec |
| Pb-Free devices. | 260°C +0/-5°C | 5sec ±1sec |

● Reliability Test Program

| Testitem | Method | Description |
|---------------|--------------|--------------------------|
| Solderability | JESD-22,B102 | 5sec , 245°C |
| Holt | JESD-22,A108 | 1000Hrs,Bias@125°C |
| PCT | JESD-22,A102 | 168Hrs,100%RH,2atm,121°C |
| TCT | JESD-22,A104 | 500Cycles, -65°C ~150°C |